

Quad 2-Input OR Gate 74AC32, 74ACT32

General Description

The AC32/ACT32 contains four, 2-input OR gates.

Features

- I_{CC} Reduced by 50% on 74AC Only
- Outputs Source/Sink 24 mA
- ACT32 Has TTL-Compatible Inputs
- These are Pb-Free and Halide Free Devices

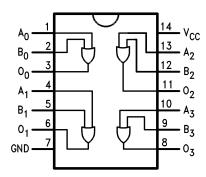


Figure 1. Connection Diagram

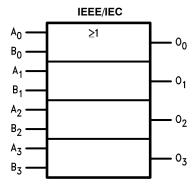


Figure 2. Logic Symbol

PIN DESCRIPTION

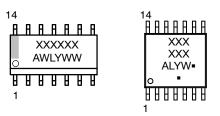
Pin Names	Description
A _n , B _n	Inputs
O _n	Outputs







MARKING DIAGRAMS



XXX = Specific Device Code
A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	Supply Voltage		-0.5 to +6.5	V
I _{IK}	DC Input Diode Current	V _I = −0.5 V	-20	mA
		$V_{I} = V_{CC} + 0.5 V$	+20	mA
V _I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V	
I _{OK}	DC Output Diode Current	V _O = -0.5 V	-20	mA
I _{OK}	DC Output Diode Current	$V_{O} = V_{CC} + 0.5 V$	+20	mA
Vo	DC Output Voltage		-0.5 to $V_{CC} + 0.5$	V
Ιο	DC Output Source or Sink Current		±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current per Output Pin		±50	mA
T _{STG}	Storage Temperature		-65 to +150	°C
TJ	Junction temperature		140	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	Supply Voltage	AC	2.0	6.0	V
		ACT	4.5	5.5	
V _I	Input Voltage		0	V _{CC}	V
V _O	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature	Operating Temperature			°C
ΔV / Δt	Minimum Input Edge Rate, AC Devices: V_{IN} from 30% to 70% of V_{CC} , V_{CC} @ 3.3 V, 4.5 V, 5.5 V		-	125	mV/ns
ΔV / Δt	Minimum Input Edge Rate, ACT Devices: V _{IN} from 0.8 V to 2.0 V, V _{CC} @ 4.5 V, 5.5 V		-	125	mV/ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC CHARACTERISTICS FOR AC

				T _A = -	+25°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	G	uaranteed Limits	Unit
V_{IH}	Minimum High Level	3.0	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	1.5	2.1	2.1	V
	Input Voltage	4.5		2.25	3.15	3.15	V
		5.5		2.75	3.85	3.85	V
V_{IL}	Maximum Low Level	3.0	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	1.5	0.9	0.9	V
	Input Voltage	4.5		2.25	1.35	1.35	V
		5.5		2.75	1.65	1.65	V
V _{OH}	Minimum High Level	3.0	I _{OUT} = -50 μA	2.99	2.9	2.9	V
	Output Voltage	4.5		4.49	4.4	4.4	V
		5.5		5.49	5.4	5.4	V
		3.0	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -12$ mA		2.56	2.46	V
		4.5	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -24$ mA		3.86	3.76	
		5.5	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -24$ mA (Note 1)		4.86	4.76	
V _{OL}	Maximum Low Level	3.0	I _{OUT} = 50 μA	0.002	0.1	0.1	V
	Output Voltage	4.5		0.001	0.1	0.1	V
		5.5		0.001	0.1	0.1	V
		3.0	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OL} = 12$ mA		0.36	0.44	V
		4.5	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OL} = 24$ mA		0.36	0.44	
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA (Note 1)		0.36	0.44	
I _{IN} (Note 3)	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND	-	±0.1	±1.0	μΑ
I _{OLD}	Minimum Dynamic Output	5.5	V _{OLD} = 1.65 V Max	-	_	75	mA
I _{OHD}	Current (Note 2)	5.5	V _{OHD} = 3.85 V Min	-	_	-75	mA
I _{CC} (Note 3)	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	-	2.0	20.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. All outputs loaded; thresholds on input associated with output under test.

2. Maximum test duration 2.0 ms, one output loaded at a time.

3. I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

DC CHARACTERISTICS FOR ACT

				T _A = -	+25°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур	G	uaranteed Limits	Unit
V _{IH}	Minimum High Level	4.5	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	1.5	2.0	2.0	V
	Input Voltage	5.5		1.5	2.0	2.0	V
V _{IL}	Maximum Low Level	4.5	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	1.5	0.8	0.8	V
	Input Voltage	5.5		1.5	0.8	0.8	V
V _{OH}	Minimum High Level	4.5	I _{OUT} = -50 μA	4.49	4.4	4.4	V
	Output Voltage	5.5		5.49	5.4	5.4	V
		4.5	$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -24$ mA		3.86	3.76	V
			$V_{IN} = V_{IL}$ or V_{IH} , $I_{OH} = -24$ mA (Note 4)		4.86	4.76	
V _{OL}		4.5	I _{OUT} = 50 μA	0.001	0.1	0.1	V
	Output Voltage	5.5		0.001	0.1	0.1	V
		4.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA		0.36	0.44	V
		5.5	V _{IN} = V _{IL} or V _{IH} , I _{OL} = 24 mA (Note 4)		0.36	0.44	
I _{IN}	Maximum Input Leakage Current	5.5	V _I = V _{CC} , GND	-	±0.1	±1.0	μΑ
I _{CCT}	Maximum I _{CC} /Input	5.5	V _I = V _{CC} - 2.1 V	0.6	_	1.5	mA
I _{OLD}	Minimum Dynamic Output	5.5	V _{OLD} = 1.65 V Max	_	-	75	mA
I _{OHD}	Current (Note 5)	5.5	V _{OHD} = 3.85 V Min	_	-	-75	mA
I _{CC}	Maximum Quiescent Supply Current	5.5	V _{IN} = V _{CC} or GND	-	4.0	40.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{4.} All outputs loaded; thresholds on input associated with output under test.5. Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS FOR AC

				λ = +25°0 L = 50 p		T _A = -40°C C _L =		
Symbol	Characteristics	V_{CC} (V) (Note 6)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	3.3	1.5	7.5	9.0	1.5	10.0	ns
		5.0	1.5	5.5	7.5	1.0	8.5	
t _{PHL}	Propagation Delay	3.3	1.5	7.0	8.5	1.0	9.0	ns
		5.0	1.5	5.0	7.0	1.0	7.5	

^{6.} Voltage range 3.3 is 3.3 V \pm 0.3 V. Voltage range 5.0 is 5.0 V \pm 0.5 V.

AC CHARACTERISTICS FOR ACT

			T _A = +25°C, C _L = 50 pF				•	
Symbol	Characteristics	V _{CC} (V) (Note 6)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns
t _{PHL}	Propagation Delay	5.0	1.0	6.5	9.0	1.0	10.0	ns

^{7.} Voltage Range 5.0 is 5.0 V \pm 0.5 V.

CAPACITANCE

Symbol	Parameter	Test Conditions	Тур	Unit
C _{IN}	Input Capacitance	V _{CC} = Open	4.5	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 5.0 V	20.0	pF

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74AC32SCX	AC32	SOIC14, Case 751EF (Pb-Free)	2500 / Tape & Reel
74AC32MTCX	AC 32	TSSOP-14 WB, Case 948G (Pb-Free)	2500 / Tape & Reel
74ACT32SC	ACT32	SOIC-14 NB, Case 751A-03 (Pb-Free)	55 Units / Tube
74ACT32SCX	ACT32	SOIC14, Case 751EF (Pb-Free)	2500 / Tape & Reel
74ACT32MTCX	ACT 32	TSSOP-14 WB, Case 948G (Pb-Free)	2500 / Tape & Reel

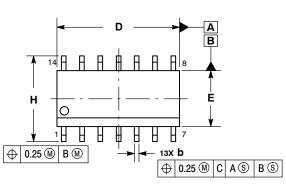
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

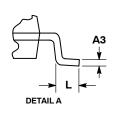


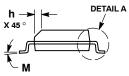
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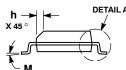
SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016





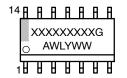




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 - DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
 - MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.35	1.75	0.054	0.068	
A1	0.10	0.25	0.004	0.010	
АЗ	0.19	0.25	0.008	0.010	
b	0.35	0.49	0.014	0.019	
D	8.55	8.75	0.337	0.344	
Е	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050	BSC	
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.019	
L	0.40	1.25	0.016	0.049	
M	0 °	7°	0 °	7 °	

GENERIC MARKING DIAGRAM*



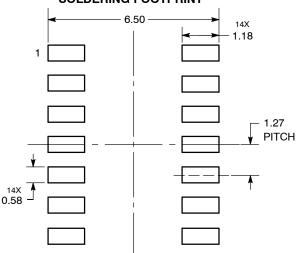
XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year = Work Week

WW = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

C SEATING PLANE

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

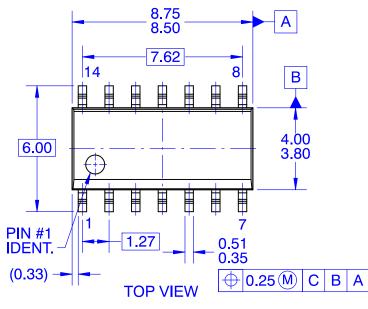
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STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

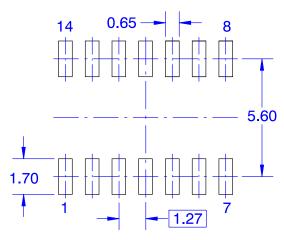
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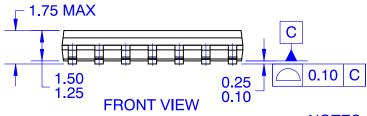
SOIC14 CASE 751EF ISSUE O

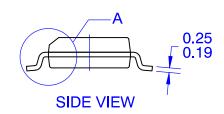
DATE 30 SEP 2016





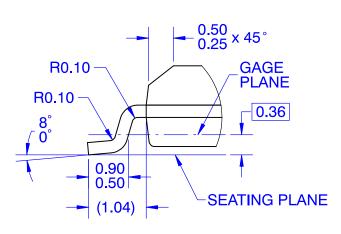
LAND PATTERN RECOMMENDATION





NOTES:

- A. CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C
 B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
- LAND PATTERN STANDARD: SOIC127P600X145-14M
- E. CONFORMS TO ASME Y14.5M, 2009

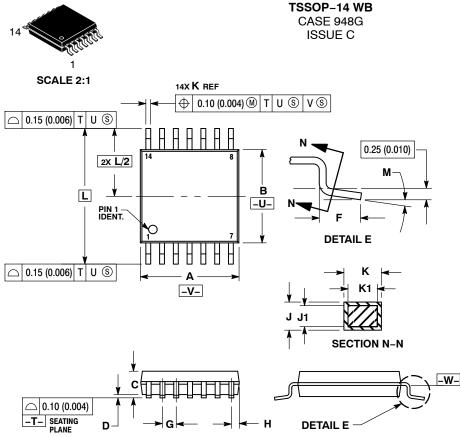


DETAIL A SCALE 16:1

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DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

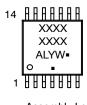
 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026	BSC
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	o°	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot V = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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